

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/053,446	01/17/2002	Janis Virbulis	VIRBULIS ET AL -1	3544
75	590 04/04/2005		EXAM	INER
COLLARD & ROE, P.C 1077 Northern Boulevard			SONG, MATTHEW J	
Roslyn, NY 1		·	ART UNIT	PAPER NUMBER
• .,	•		1722	
			DATE MAILED: 04/04/2004	5

Please find below and/or attached an Office communication concerning this application or proceeding.

		(
	Application No.	Applicant(s)
	10/053,446	VIRBULIS ET AL.
Office Action Summary	Examiner	Art Unit
	Matthew J Song	1722
The MAILING DATE of this communication appeared for Reply		
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a repl - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a rely within the statutory minimum of thin will apply and will expire SIX (6) MONe, cause the application to become AE	reply be timely filed ty (30) days will be considered timely. ITHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).
Status [.]		,
1) Responsive to communication(s) filed on 20 J	lanuary 2005.	
2a)⊠ This action is FINAL . 2b)□ This	s action is non-final.	
3) Since this application is in condition for allowa	ince except for formal matt	ers, prosecution as to the merits is
closed in accordance with the practice under I	Ex parte Quayle, 1935 C.C). 11, 453 O.G. 213.
Disposition of Claims		
4) Claim(s) 1.2.14.17 and 18 is/are pending in the 4a) Of the above claim(s) is/are withdra		
5) Claim(s) is/are allowed.		
6) Claim(s) <u>1, 2, 14, 17 and 18</u> is/are rejected.		
7) Claim(s) is/are objected to.		
8) Claim(s) are subject to restriction and/o	or election requirement.	
Application Papers		
9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) accomposed and applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Example 11.	cepted or b) objected to drawing(s) be held in abeyaretion is required if the drawing	nce. See 37 CFR 1.85(a). (s) is objected to. See 37 CFR 1.121(d).
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Burea	ts have been received. ts have been received in A prity documents have been	application No
* See the attached detailed Office action for a list	• • • • • • • • • • • • • • • • • • • •	received.
Attachment(s)	🗖	
1)		Summary (PTO-413) s)/Mail Date
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date		nformal Patent Application (PTO-152)

Art Unit: 1722

DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

2. Claims 1-2 and 17-18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Tamatsuka et al (US 6,139,625) in view of Luter et al (US 6,053,974) along with Aratani (DE 3701811), an English Abstract has been provided.

Tamatsuka et al discloses 8-inch diameter (203.2 mm) silicon single crystal ingots were pulled by the Czochralski method with an oxygen concentration of 0.7x10¹⁸ atoms/cm³ or more (Table 1) from a silicon melt in a quartz crucible with a diameter of 18 inches (457.2 mm) (col 8, ln 1 to col 9, ln 65).

Tamatsuka et al does not disclose a heat shield above the crucible.

Art Unit: 1722

In a method of forming a single crystal by the Czochralski method, note entire reference, Luter et al teaches a heat shield 40 mounted above the surface of a molten source material for growing ingots with a diameter of about 220 mm (Fig 1, col 4, ln 1-67 and col 5, ln 1-15). Luter et al also teaches the overall gradient at the surface is reduced which reduces the number of defects at the surface and the distribution of defects is more even throughout the ingot for ingots produced with the heat shield (col 7, ln 1-15). It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify Tamatsuka et al with Luter et al's heat shield to reduce defects in the ingot.

The combination of Tamatsuka et al and Luter et al is silent to exposing the silicon melt to an influence of a traveling magnetic filed which exerts a substantially vertically orientated force on the melt in a region of the crucible wall.

In a method of producing a single crystal using the Czochralski method, Aratani teaches applying a downwardly traveling magnetic field to the melt in the crucible, this reads on applicants' vertically oriented force. Aratani also discloses a single magnetic field application device 8, note Figure 1, this reads on applicants' except for the traveling magnetic field no further magnetic field being applied to the melt.

Travelling magnetic field are known in the art to be advantageous in minimizing dissolution of oxygen from the silica material of a crucible and for stirring a melt in Czochralski processes, as evidenced by Aratani (DE 3701733) and Szekely et al (US 5,196,085) below.

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of the invention to modify the combination of Tamatsuka et al and Luter et al by applying a traveling

magnetic field, as taught by Aratani to minimize dissolution of oxygen from the silica of the crucible and for stirring the melt, which is desirable.

Referring to claim 1, the combination of Tamatsuka et al, Luter et al, and Aratani teach pulling a silicon ingot with a diameter of 8 inches from a 18 inch crucible, a heat shield for reducing defects and vertical magnetic field to eliminate flow instabilities. Also, the combination of Tamatsuka et al, Luter et al, and Aratani teaches a magnetic field with an intensity of 20-200 Gauss ('811 Fig 7), which is equivalent to 2-20 mT. The magnetic field intensity taught by the combination of Tamatsuka et al, Luter et al, and Aratani is within the range taught by applicant. 2-15 mT (page 10 of the instant specification); therefore inherently has an intensity sufficient to attenuate low-frequency temperature fluctuations in the melt.

Referring to claim 2, the combination of Tamatsuka et al, Luter et al, and Aratani teach oxygen concentrations of 0.7x10¹⁸ atoms/cm³ or more

Referring to claim 17, the combination of Tamatsuka et al, Luter et al, and Aratani teaches an upward force (aufwärtsFluß) ('811 col 5, ln 1-15).

Referring to claim 18, the combination of Tamatsuka et al, Luter et al, and Aratani teaches a downward force ('811 Abstract)

3. Claims 14 is rejected under 35 U.S.C. 103(a) as being unpatentable over Tamatsuka et al (US 6,139,625) in view of Luter et al (US 6,053,974) along with Aratani (DE 3701811), an English Abstract has been provided, as applied to claims 1-2 and 17-18 above, and further in view of Lari et al.(US 4,905,756) or Morishita et al (JP 61-029128), an English Abstract has been provided.

Art Unit: 1722

The combination of Tamatsuka et al, Luter et al and Aratani teach all of the limitations of claim 14, except the traveling magnetic is due to three coils which are connected to a 3-phase power supply and the traveling magnetic field exerts a substantially vertically oriented force on the melt is generated by suitable selection of an order of connections; and the connections of the coils have a phase angle in an order of 0°-60°-120° or 0°-120°-240°. The combination of Tamatsuka et al, Luter et al and Aratani teaches providing a traveling magnetic field but is silent to the means of producing the magnetic field

In an apparatus for producing magnetic fields, note entire reference, Lari et al teaches a magnetic field traveling wave is produced with only two coil layers with current 180° out of phase and in the preferred embodiment, three coil layers 120° out of phase are used, this reads on applicant connections of the coils have a phase angle in an order of 0°-120°-240°. Lari et al also teaches an AC source supplies three-phase alternating current. Also, additional coil waves could de used to produce a traveling wave, for example four coils 90° out of phase. It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify the combination of Tamatsuka et al, Luter et al and Aratani with Lari et al's means of producing a traveling magnetic field because selection of a known material based on its suitability for its intended use is held to be obvious (MPEP 2144.07).

In an apparatus for providing a magnetic field, Morishita et al teaches a magnetic generator made of a coil 30, which is formed of coils 31a, 31b 31c. And when a 3-phase AC current having 120° different positions are respectively flowed to the coils, a traveling magnetic field which moves in a prescribed direction is generated (Abstract), this reads on applicant connection of the coils have a phase angle in an order of 0°-120°-240°. It would have been

Art Unit: 1722

obvious to a person of ordinary skill in the art at the time of the invention to modify the combination of Tamatsuka et al, Luter et al and Aratani with Morishita et al's means of producing a traveling magnetic field because selection of a known material based on its suitability for its intended use is held to be obvious (MPEP 2144.07).

Response to Arguments

- 4. Applicant's arguments, see page 6 of the remarks, filed 1/20/2005, with respect to the USC 112, first paragraph rejection have been fully considered and are persuasive. The rejection of claims 1 and 14 has been withdrawn. The amendment has overcome the rejection.
- 5. Applicant's arguments, see page 9 of the remarks, filed 1/20/2005, with respect to Szekely et al have been fully considered and are persuasive. The rejection of claim 4 has been withdrawn. The amendment has overcome the rejection.
- 6. Applicant's arguments filed 1/20/2005 have been fully considered but they are not persuasive.

In response to applicant's argument that the references fail to show certain features of applicant's invention, it is noted that the features upon which applicant relies (i.e., applying the traveling magnetic field with sufficient intensity in order to produce enhanced convection (pg 8)) are not recited in the rejected claim(s). Although the claims are interpreted in light of the specification, limitations from the specification are not read into the claims. See In re Van Geuns, 988 F.2d 1181, 26 USPQ2d 1057 (Fed. Cir. 1993).

Art Unit: 1722

In response to applicant's argument that the prior art does not teach applying a magnetic field with an intensity sufficient to attenuate low-frequency temperature fluctuations in the melt, the fact that applicant has recognized another advantage which would flow naturally from following the suggestion of the prior art cannot be the basis for patentability when the differences would otherwise be obvious. See *Ex parte Obiaya*, 227 USPQ 58, 60 (Bd. Pat. App. & Inter. 1985). Aratani teaches applying a magnetic field with an intensity of 20-200 Gauss (2-20 mT), which is sufficient to obtain the claimed effect because applicant teaches using a magnetic field with an intensity of 1-15 mT, note page 10 of the instant specification.

Conclusion

7. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Aratani (DE 3701733) teaches applying a traveling magnetic field to a melt in a Czochralski process minimizes dissolution of oxygen from silica material of a crucible (Abstract).

Szekely et al (US 5,196,085) teaches a CZ growing system with an axial magnetic filed in the vicinity of the melt-crystal interface and melt stirring can be accomplished magnetically by inducing vertical motion with a traveling field (col 2, ln 1-67) and vertical magnetic fields are useful for stabilizing flow (col 1, ln 5-62).

Wilson et al (US 6,284,384) teaches $5x10^{17}$ atoms per cm³ is equivalent to 10 oxygen atoms per million total atoms in the wafer (col 8, ln 64 to col 9, ln 15).

Art Unit: 1722

Nanaka (JP 62-070286) teaches a magnetic field directed downward (Fig 1) and a magnetic field directed upward (Fig 4), note abstract.

Iida et al (US 6,077,343) teaches a Czochralski method employing a heat shield and a magnetic field (col 10, ln 1-67).

Kawanishi et al (US 6,086,671) teaches a magnetic field directed upward a crucible wall (col 3, ln 1-67).

Crowley et al (US 4,808,079) teaches at least two coils which are electrically connected to a three-phase power source is used to produce a traveling magnetic field (col 2, ln 25-35 and col 3, ln 1-20).

Ou-Yang (US 6,636,037) teaches a traveling magnetic field is provided by three coils driven by a phase that is 120° offset from the last phase signal (col 7, ln 1-50).

8. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event,

Art Unit: 1722

however, will the statutory period for reply expire later than SIX MONTHS from the date of this

Page 9

final action.

9. Any inquiry concerning this communication or earlier communications from the examiner

should be directed to Matthew J Song whose telephone number is 571-272-1468. The examiner

can normally be reached on M-F 9:00-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Benjamin Utech can be reached on 571-272-1137. The fax phone number for the

organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

may be obtained from either Private PAIR or Public PAIR. Status information for unpublished

applications is available through Private PAIR only. For more information about the PAIR

system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR

system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

MJS

March 29, 2005

Matthew J Song

Examiner

Art Unit 1722

ROBERT KUNEMUND

PHIMARY EXAMINER